

Low Power Peak EMI Reducing Solution

Features

- Generates an EMI optimized clock signal at the output.
- Integrated loop filter components.
- Operates with a 3.3 / 2.5V Supply.
- Operating current less than 5mA.
- Low power CMOS design.
- Input frequency range: 30MHz to 50MHz for 2.5V.
 : 30MHz to 50MHz for 3.3V.
- Generates a 1X low EMI spread spectrum clock of the input frequency.
- Frequency deviation: ±0.75% (Typ) @46MHz
 Input Frequency.
- Available in 6 pin TSOT-23, 8 pin SOIC and 8 pin TSSOP Packages.

Product Description

The ASM3P2780A is a versatile spread spectrum frequency modulator designed specifically for a wide range of clock frequencies. The ASM3P2780A reduces electromagnetic interference (EMI) at the clock source, allowing system wide reduction of EMI of all clock dependent signals. The ASM3P2780A allows significant system cost savings by reducing the number of circuit board layers ferrite beads, shielding that are traditionally required to pass EMI regulations.

The ASM3P2780A uses the most efficient and optimized modulation profile approved by the FCC and is implemented by using a proprietary all digital method.

The ASM3P2780A modulates the output of a single PLL in order to "spread" the bandwidth of a synthesized clock, and more importantly, decreases the peak amplitudes of its harmonics. This results in significantly lower system EMI compared to the typical narrow band signal produced by oscillators and most frequency generators. Lowering EMI by increasing a signal's bandwidth is called 'spread spectrum clock generation'.

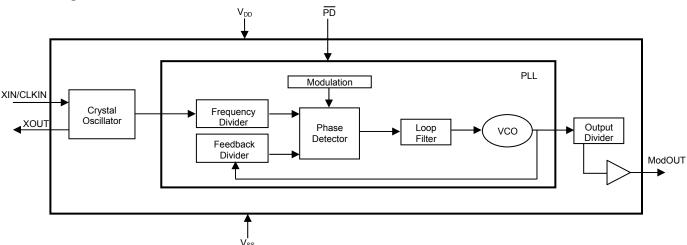
Applications

The ASM3P2780A is targeted towards all portable devices with very low power requirements like MP3 players and digital still cameras.

Key Specifications

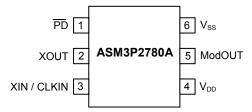
Description	Specification
Supply voltages	V _{DD} = 3.3V / 2.5V
Cycle-to-Cycle Jitter	200pS (Max)
Output Duty Cycle	45/55%
Modulation Rate Equation	F _{IN} /1280
Frequency Deviation	±0.75 (Typ) @ 46MHz

Block Diagram





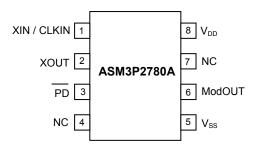
Pin Configuration (6-pin TSOT- 23 Package)



Pin Description

Pin#	Pin Name	Туре	Description			
1	— PD	I	Power-down control pin. Pull low to enable power-down mode. Connect to V _{DD} if not used.			
2	XOUT	0	Crystal connection. If using an external reference, this pin must be left unconnected.			
3	XIN / CLKIN	I	Crystal connection or external reference frequency input. This pin has dual functions. It can be connected either to an external crystal or an external reference clock.			
4	V_{DD}	Р	Power supply for the entire chip.			
5	ModOUT	0	Spread spectrum clock output.			
6	V _{SS}	Р	Ground connection.			

Pin Configuration (8-pin SOIC and TSSOP Packages)

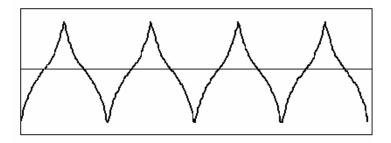


Pin Description

Pin#	Pin Name	Type	Description
1	XIN/CLKIN	I	Crystal connection or external reference frequency input. This pin has dual functions. It can be connected either to an external crystal or an external reference clock.
2	XOUT	0	Crystal connection. If using an external reference, this pin must be left unconnected.
3	— PD	I	Power-down control pin. Pull low to enable power-down mode. Connect to VDD if not used.
4	NC	-	No connect.
5	V _{SS}	Р	Ground connection.
6	ModOUT	0	Spread spectrum clock output.
7	NC	-	No connect.
8	V_{DD}	Р	Power supply for the entire chip.



Modulation Profile



Specifications

Description		Specification	
_	For 2.5V Supply	20141 - 21411 - 52141	
Frequency Range	For 3.3V Supply	30MHz < CLKIN < 50MHz	
Modulation Equation		F _{IN} /1280	
Frequency Deviation		±0.75% (Typ) @ 46MHz	

Absolute Maximum Ratings

Symbol	Parameter	Rating	Unit				
V_{DD},V_{IN}	Voltage on any pin with respect to Ground	-0.5 to +4.6	V				
T_{STG}	Storage temperature	-65 to +125	°C				
T _A	Operating temperature	0 to 70	°C				
Ts	Max. Soldering Temperature (10 sec)	260	°C				
TJ	Junction Temperature	150	°C				
T _{DV} Static Discharge Voltage 2 KV (As per JEDEC STD22- A114-B)							
	Note: These are stress ratings only and are not implied for functional use. Exposure to absolute maximum ratings for prolonged periods of time may affect device reliability						



DC Electrical Characteristics for 2.5V Supply (Test condition: All parameters are measured at room temperature (+25°C) unless otherwise stated)

Symbol	Parameter	Min	Тур	Max	Unit
V_{IL}	Input low voltage	V _{SS} - 0.3	-	0.8	V
V_{IH}	Input high voltage	2.0	-	V _{DD} + 0.3	V
IιL	Input low current	-	-	-35	μΑ
I _{IH}	Input high current	-	-	35	μΑ
I _{XOL}	XOUT output low current (@0.6V, V _{DD} =2.5V)	-	3	-	mA
I _{XOH}	XOUT output high current (@1.8V, V _{DD} =2.5V)	-	3	-	mA
V _{OL}	Output low voltage (V _{DD} = 2.5 V, I _{OL} = 8mA)	-	-	0.6	V
V _{OH}	Output high voltage (V _{DD} = 2.5 V, I _{OH} = 8mA)	1.8	-	-	V
I _{DD}	Static supply current*	-	-	10	uA
Icc	Dynamic supply current (2.5V, 46MHz and no load)	-	4.0	-	mA
V_{DD}	Operating Voltage	2.375	2.5	2.625	V
t _{ON}	Power-up time (first locked cycle after power-up)**	-	_	5	mS
Z _{out}	Output impedance	-	50	-	Ω
* XIN /CLKIN	N pin and PD pin are pulled low				

^{**} V_{DD} and XIN/CLKIN input are stable, PD pin is made high from low.

AC Electrical Characteristics for 2.5V Supply

Symbol	Parameter			Тур	Max	Unit
CLKIN	Input frequency		30	-	50	MHz
ModOUT	Output frequency		30	-	50	MHz
f _d	Frequency Deviation	Input Frequency = 30MHz	-	± 1.10	ı	%
¹d	Input Frequency = 50MHz	-	± 0.65	-	70	
t _{LH} *	Output rise time (measured f	rom 0.7V to 1.7V)	0.7	1.3	1.6	nS
t _{HL} *	Output fall time (measured fr	om 1.7V to 0.7V)	0.4	0.8	1.0	nS
t _{JC}	Jitter (cycle to cycle)		-	-	200	pS
t _D	Output duty cycle		45	50	55	%
* t _{LH} and t _{HL} are measured into a capacitive load of 15pF						



DC Electrical Characteristics for 3.3V Supply (Test condition: All parameters are measured at room temperature (+ 25°C) unless otherwise stated)

Symbol	Parameter	Min	Тур	Max	Unit			
V _{IL}	Input low voltage	V _{SS} - 0.3	-	0.8	V			
V _{IH}	Input high voltage	2.0	-	V _{DD} + 0.3	V			
I _{IL}	Input low current	-	-	-35	μA			
I _{IH}	Input high current	-	-	35	μA			
I _{XOL}	XOUT output low current (@0.4V, V _{DD} =3.3V)	-	3	-	mA			
I _{XOH}	XOUT output high current (@2.5V, V _{DD} =3.3V)	-	3	-	mA			
V _{OL}	Output low voltage (V _{DD} = 3.3 V, I _{OL} = 8mA)	-	-	0.4	V			
V _{OH}	Output high voltage ($V_{DD} = 3.3 \text{ V}$, $I_{OH} = 8\text{mA}$)	2.5	-	-	V			
I _{DD}	Static supply current*	-	-	10	uA			
I _{CC}	Dynamic supply current (3.3V, 46MHz and no load)	-	5.0	-	mA			
V_{DD}	Operating Voltage	2.7	3.3	3.6	V			
t _{ON}	Power-up time (first locked cycle after power-up)**	-	-	5	mS			
Z _{OUT}	Output impedance	-	45	-	Ω			
	* XIN /CLKIN pin and PD pin are pulled low							

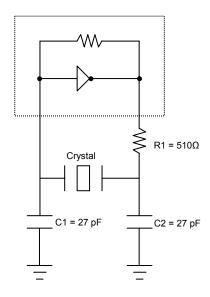
^{**} V_{DD} and XIN/CLKIN input are stable, PD pin is made high from low.

AC Electrical Characteristics for 3.3V Supply

Symbol	Pai	Min	Тур	Max	Unit	
CLKIN	Input frequency		30	-	50	MHz
ModOUT	Output frequency		30	-	50	MHz
f.	Fraguency Deviation	Input Frequency = 30MHz	-	±1.10	-	%
f _d	Frequency Deviation Input Frequency = 50MHz		-	± 0.65	-	70
t _{LH} *	Output rise time (measured	Output rise time (measured from 0.8 to 2.0V)			1.4	nS
t _{HL} *	Output fall time (measured	at 2.0V to 0.8V)	0.3	0.8	1.1	nS
t _{JC}	Jitter (cycle to cycle)		-	-	200	pS
t _D	Output duty cycle			50	55	%
*t _{LH} and t _{HL} are measured into a capacitive load of 15pF						



Typical Crystal Oscillator Circuit



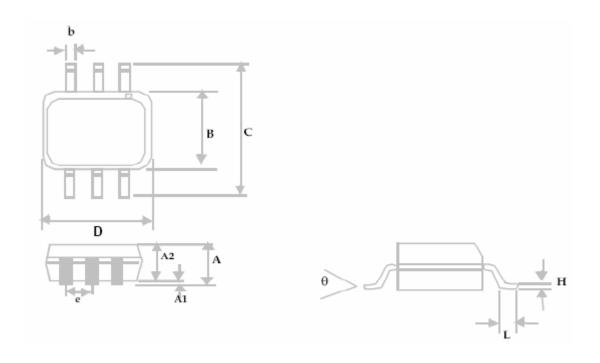
Typical Crystal Specifications

Fundamental AT cut parallel resonant crystal				
Nominal frequency	33MHz			
Frequency tolerance	± 50ppm or better at 25°C			
Operating temperature range	-25°C to +85°C			
Storage temperature	-40°C to +85°C			
Load capacitance	18pF			
Shunt capacitance	7pF maximum			
ESR	25Ω			



Package Information

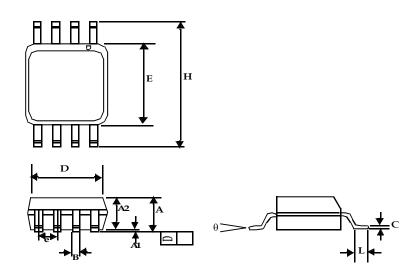
6-pin TSOT-23 Package



	Dimensions				
Symbol	In	ches	Milli	meters	
	Min	Max	Min	Max	
Α		0.04		1.00	
A1	0.00	0.004	0.00	0.10	
A2	0.033	0.036	0.84	0.90	
b	0.012	0.02	0.30	0.50	
Н	0.00	05 BSC	0.127 BSC		
D	0.11	14 BSC	2.9	0 BSC	
В	0.0	6 BSC	1.6	0 BSC	
е	0.03	74 BSC	0.95	50 BSC	
С	0.11 BSC		2.8	0 BSC	
L	0.0118	0.02	0.30	0.50	
θ	0°	4°	0°	4°	



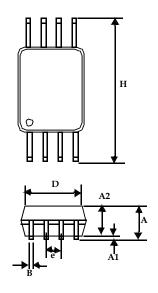
8-Pin SOIC Package

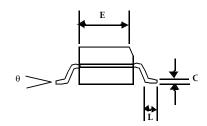


	Dimensions				
Symbol	Inc	hes	Millimeters		
	Min	Max	Min	Max	
A1	0.004	0.010	0.10	0.25	
А	0.053	0.069	1.35	1.75	
A2	0.049	0.059	1.25	1.50	
В	0.012	0.020	0.31	0.51	
С	0.007	0.010	0.18	0.25	
D	0.193	BSC	4.90	D BSC	
E	0.154	BSC	3.9	1 BSC	
е	0.050	BSC	1.2	7 BSC	
Н	0.236	BSC	6.00 BSC		
L	0.016	0.050	0.41	1.27	
θ	0°	8°	0°	8°	



8-Pin TSSOP Package





	Dimensions			
Symbol	Inches		Millimeters	
	Min	Max	Min	Max
Α		0.043		1.10
A1	0.002	0.006	0.05	0.15
A2	0.033	0.037	0.85	0.95
В	0.008	0.012	0.19	0.30
С	0.004	0.008	0.09	0.20
D	0.114	0.122	2.90	3.10
E	0.169	0.177	4.30	4.50
е	0.026 BSC		0.65 BSC	
Н	0.252 BSC		6.40 BSC	
L	0.020	0.028	0.50	0.70
θ	0°	8°	0°	8°

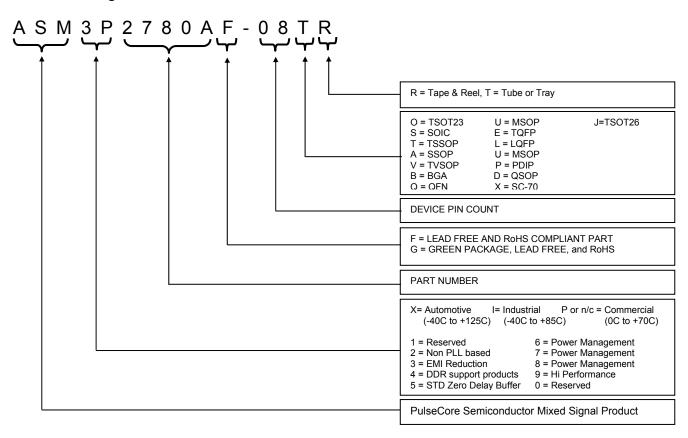


Ordering Information

Part Number	Marking	Package Type	Temperature
ASM3P2780AF-06OR	G4LL	6-Pin TSOT-23, TAPE & REEL, Pb Free	Commercial
ASM3P2780AF-08TT	3P2780AF	8-Pin TSSOP, TUBE, Pb Free	Commercial
ASM3P2780AF-08TR	3P2780AF	8-Pin TSSOP, TAPE & REEL, Pb Free	Commercial
ASM3P2780AF-08ST	3P2780AF	8-Pin SOIC, TUBE, Pb Free	Commercial
ASM3P2780AF-08SR	3P2780AF	8-Pin SOIC, TAPE & REEL, Pb Free	Commercial
ASM3P2780AG-06OR	G3LL	6-Pin TSOT-23, TAPE & REEL, Green	Commercial
ASM3P2780AG-08TT	3P2780AG	8-Pin TSSOP, TUBE, Green	Commercial
ASM3P2780AG-08TR	3P2780AG	8-Pin TSSOP, TAPE & REEL, Green	Commercial
ASM3P2780AG-08ST	3P2780AG	8-Pin SOIC, TUBE, Green	Commercial
ASM3P2780AG-08SR	3P2780AG	8-Pin SOIC, TAPE & REEL, Green	Commercial
ASM3I2780AF-06OR	G5LL	6-Pin TSOT-23, TAPE & REEL, Pb Free	Industrial
ASM3I2780AF-08TT	3I2780AF	8-Pin TSSOP, TUBE, Pb Free	Industrial
ASM3I2780AF-08TR	3I2780AF	8-Pin TSSOP, TAPE & REEL, Pb Free	Industrial
ASM3I2780AF-08ST	3I2780AF	8-Pin SOIC, TUBE, Pb Free	Industrial
ASM3I2780AF-08SR	3I2780AF	8-Pin SOIC, TAPE & REEL, Pb Free	Industrial
ASM3I2780AG-06OR	G6LL	6-Pin TSOT-23, TAPE & REEL, Green	Industrial
ASM3I2780AG-08TT	3I2780AG	8-Pin TSSOP, TUBE, Green	Industrial
ASM3I2780AG-08TR	3I2780AG	8-Pin TSSOP, TAPE & REEL, Green	Industrial
ASM3I2780AG-08ST	3I2780AG	8-Pin SOIC, TUBE, Green	Industrial
ASM3I2780AG-08SR	3I2780AG	8-Pin SOIC, TAPE & REEL, Green	Industrial



Device Ordering Information



Licensed under U.S Patent Nos 5,488,627 and 5,631,921







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Note: This product utilizes US Patent # 6,646,463 Impedance Emulator Patent issued to PulseCore Semiconductor, dated 11-11-2003

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